Photocouplers GaAłAs Infrared LED & Photo IC

TLP5214

±4.0 A (max)

3.5 mA (max)

15 V to 30 V

150 ns (max)

±35 kV/μs (min) 5000 Vrms (min)

-40°C to 110°C

 $I_{FLH} = 6 \text{ mA} (\text{max})$

Isolated IGBT/Power MOSFET gate drive AC and brushless DC motor drives Industrial Inverters and Uninterruptible Power Supply (UPS)

The TLP5214 is a highly integrated 4.0A output current IGBT gate drive photocoupler housed in a long creepage and clearance SO16L package.

The TLP5214, a smart gate driver photocoupler, includes functions of IGBT desaturation detection, isolated fault status feedback, soft IGBT turn-off, active Miller cramping and under voltage lockout (UVLO).

This photocoupler is suitable for driving IGBT and power MOSFET used in inverter applications.

The TLP5214 consists two GaAlAs infrared light-emitting diodes (LEDs) and two high-gain and high-speed ICs. They realize high current, high-speed output control and output fault status feedback.

- Peak output current:
- Guaranteed performance over temperature:
- Supply current:
- Power supply voltage:
- Threshold input current:
- Switching time (tpLH / tpHL) :
- Common mode transient immunity:
- Isolation voltage:
- UL approved : UL1577, File No.E67349
- c-UL approved :CSA Component Acceptance Service No. 5A, File No.E67349
- Option (D4) VDE approved : DIN EN60747-5-5(Note)

EN60065 or EN60950-1, EN62368-1

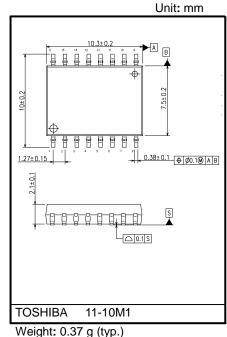
CQC-approved: GB4943.1, GB8898 Japan Factory

Note : When a EN60747-5-5 approved type is needed, please designate "Option(D4)"

Truth Table

1-	UVLO	DESAT	FAULT	V	
I _F	(V _{CC2} -V _E)	(14Pin DESAT Terminal Input)	(3Pin FAULT Terminal Output)	Vo	
OFF	Not Active ($> V_{UVLO}^+$)	Not Active	High	Low	
ON	Not Active ($> V_{UVLO}^+$)	Low (< V _{DESATth})	High	High	
ON	Not Active ($> V_{UVLO}^+$)	High (> V _{DESATth})	Low (FAULT)	Low	
ON	Active (< V _{UVLO} ⁻)	Not Active	High	Low	
OFF	Active (< V _{UVLO} ⁻)	Not Active	High	Low	

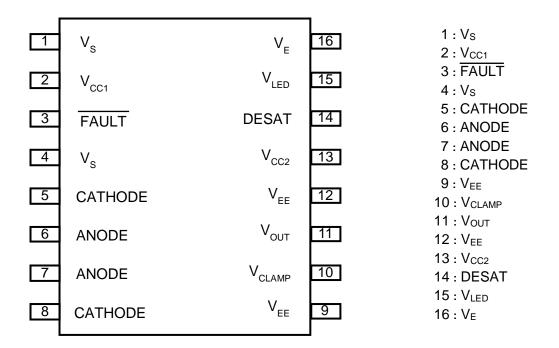
Start of commercial production 2014-05 2015-12-26



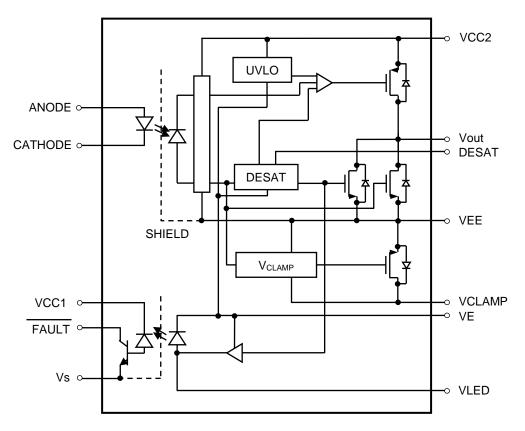
Construction mechanical rating

	SO16L
Height	2.3 mm (max)
Creepage Distance	8.0 mm (min)
Clearance	8.0 mm (min)
Insulation Thickness	0.4 mm (min)

Pin Configuration (top view)



Internal Circuit



Note: A 1- μ F bypass capacitor must be connected between pins 9 and 13, pins 13 and 16.

Absolute Maximum Ratings (Note) (Ta = 25°C ,Unless otherwise specified)

	Characteristic	Symbol	Rating	Unit	
LED	Input forward current	lF	25	mA	
	Input forward current derating (Ta ≥	95°C)	∆l _F /∆Ta	-1	mA/°C
	Peak transient input forward current	(Note 1)	IFPT	1	A
	Peak transient input forward current of	lerating (Ta ≥ 95°C)	ΔIFPT/ΔTa	-25	mA/°C
	Reverse Input Voltage		V _R	6	V
	Input power dissipation		PD	145	mW
	Input power dissipation derating (Ta	≥ 95°C)	$\Delta P_D / \Delta Ta$	-5.0	mW/°C
Detector	Positive Input Supply Voltage		V _{CC1}	-0.5 to 7	V
	"H" peak output current	Ta = -40 to 110 °C	Іорн	-4.0	А
	"L" peak output current	(Note 2)	IOPL	+4.0	А
	FAULT Output Current		IFAULT	8	mA
	FAULT Pin Voltage	V _{FAULT}	-0.5 to V _{CC1}	V	
	Total Output Supply Voltage		(V _{CC2} –V _{EE})	-0.5 to 35	V
	Negative Output Supply Voltage		(V _E –V _{EE})	-0.5 to 15	V
	Positive Output Supply Voltage		(V _{CC2} –V _E)	–0.5 to 35 – (V _E –V _{EE})	V
	Output voltage		Vo	-0.5 to V _{CC2}	V
	Peak Clamping Sinking Current		I _{Clamp}	1.7	А
	Miller Clamping Pin Voltage		V _{Clamp}	-0.5 to V _{CC2}	V
	DESAT Voltage		V _{DESAT}	V_E to V_E + 10	V
	Output power dissipation		Po	410	mW
	Output power dissipation (Ta ≥ 95°C	∆ P _O /∆Ta	-14.0	mW/°C	
Common	Operating temperature range		Topr	-40 to 110	°C
	Storage temperature range	Tstg	-55 to 125	°C	
	Lead soldering temperature (10 s)	(Note 3)	Tsol	260	°C
	Isolation voltage (AC, 60 s, R.H. ≤ 60	%) (Note 4)	BVS	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note: A ceramic capacitor (1 μ F) should be connected between pins 9 and 13, pins 13 and 16 to stabilize the operation of the high gain linear amplifier.Furthermore, in case V_E-V_{EE} > 0 V, a bypass capacitor, which has good high frequency characteristic, a ceramic capacitor (1 μ F) should be connected between pins 9 and 16. Failure to provide the bypassing may impair the switching property. The total lead length between capacitor and coupler should not exceed 1 cm.
- Note 1: Pulse width $P_W \le 1 \ \mu s$, 300 pps
- Note 2: Exponential waveform pulse width $P_W \leq$ 0.2 $\mu s,\, f \leq$ 15 kHz, V_{CC} = 15 V
- Note 3: For the effective lead soldering area.
- Note 4: This device considered a two-terminal device: All pins on the LED side are shorted together, and all pin on the photodetector side are shorted together.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Min	Тур.	Max	Unit
Total Output Supply Voltage (Note 5)	$(V_{CC2} - V_{EE})$	15	-	30	V
Negative Output Supply Voltage	(V _E -V _{EE})	0	-	15	V
Positive Output Supply Voltage	$(V_{CC2} - V_E)$	15	-	$30 - (V_{E} - V_{EE})$	V
Input On-State Current (Note 6)	I _{F(ON)}	7.5	-	12	mA
Input Off-State Voltage	V _{F(OFF)}	0	-	0.8	V
Operating frequency (Note 7)	f	-	-	50	kHz

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Note 5: If the Vcc rise slope is sharp, an internal circuit might not operate with stability. Please design the Vcc rise slope under 3.0 V / μ s.

Note 6: Input signal rise time (fall time) \leq 0.5 µs.

Note 7: Exponential waveform. $I_{OPH} \ge -4.0 \text{ A} (\le 90 \text{ ns}), I_{OPL} \le 4.0 \text{ A} (\le 90 \text{ ns}), Ta = 110^{\circ}\text{C}$

Electrical Characteristics (Note) (Ta = -40 to 110 °C, unless otherwise specified)

Characteristics	Symbol	Test Circuit	Test Condition	Min	Typ.*	Max	Unit
Input Forward Voltage	V _F	-	I⊧ = 10 mA, Ta = 25°C	1.4	-	1.7	V
Input Reverse Current	I _R	-	V _R = 5 V	-	-	10	μΑ
Input Capacitance	Ct	_	V=0 V, f=1 MHz, Ta = 25°C	-	95	-	pF
FAULT Low Level Output Voltage	VFAULTL		IFAULT = 1.1 mA, V _{CC} 1=5.5 V	-	0.2	0.4	v
FAOLT LOW Level Output Voltage	VFAULIL	_	$I_{FAULT} = 1.1 \text{ mA}, V_{CC}1=3.3 \text{ V}$	-	0.2	0.4	v
EALILE High Lovel Output Current			$V_{FAULT} = 5.5 \text{ V}, V_{CC}1 = 5.5 \text{ V}, Ta = 25^{\circ}C$	-	-	0.5	
FAULT High Level Output Current	IFAULTH	_	V _{FAULT} = 5.5 V, V _{CC} 1 = 3.3 V, Ta = 25°C	-	-	0.3	μA
High Level Output Current (Note 8)		1	$V_0 = V_{CC}2 - 4 V$	-	-4.0	-1.2	
	I _{OPH}	I	$V_0 = V_{CC}2 - 7 V$	-	-6.5	-3.0	^
Low Level Output Current (Note 8)		2	$V_O = V_{EE} + 2.5 \ V$	1.2	3.5	-	A
	I _{OPL}	2	$V_O = V_{EE} + 7 \ V$	3	5.5	-	
Low Level Output Current			V _O - V _{FF} = 14 V	90	150	230	
During Fault Condition	I _{OLF}		$v_0 - v_{EE} = 14 v$	90	150	230	mA
High Level Output Voltage	V _{OH}	3	I ₀ = -100 mA	V _{CC} 2-0.3	V _{CC} 2-0.2	-	
Low Level Output Voltage	V _{OL}	4	l _o = 100 mA	-	0.1	0.2	V
Clamp Pin Threshold Voltage	V_{tClamp}		_	-	3.0	-	
Clamp Low Level Sinking Current	I _{CL}		$V_O = V_{EE} + 2.5 \ V$	0.56	1.8	-	А
High Level Supply Current	I _{CC2H}	5	$I_0 = 0 \text{ mA}$	-	2.4	3.5	
Low Level Supply Current	I _{CC2L}	6	$I_0 = 0 \text{ mA}$	-	2.3	3.5	mA
Blanking Capacitor Charging Current	I _{CHG}	7	V _{DESAT} = 2 V	-0.13	-0.24	-0.33	mA
Blanking Capacitor Discharge Current	I _{DSCHG}	8	V _{DESAT} = 7 V	10	49	-	
DESAT Threshold Voltage	V _{DESAT}	_	Vcc2-VE>VUVLO-	6	6.5	7.5	
	V_{UVLO}^{+}	9	V ₀ >5 V	10.5	11.6	13.5	v
UVLO Threshold Voltage	V _{UVLO} -	9	V ₀ <5 V	9.2	10.3	11.1	v
UVLO hysteresis	UVLO _{HYS}	—	_	-	1.3	-	

(*): All typical values are at $Ta = 25^{\circ}C$

Note 8: I₀ application time \leq 50 µs, 1 pulse

Electrical Characteristics (Note) (Ta = -40 to 110 °C, unless otherwise specified)

Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.*	Max	Unit
Threshold Input Current(L/H)	IFLH	10	$V_{CC}=30~V,~V_O<5~V$	-	0.8	6	mA
Threshold Input Voltage (H/L)	VFHL	-	V _{CC} = 30 V, V _O > 5 V	0.8	-	-	V

(*): All typical values are at $Ta = 25^{\circ}C$

Note: This product is more sensitive than conventional products to electrostatic discharge (ESD) owing to its low power consumption design.

It is therefore all the more necessary to observe general precautions regarding ESD when handling this component.

Isolation Characteristics (Note) (Ta = 25 °C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit	
Capacitance input to output	Cs	Vs = 0 V, f = 1 MHz	-	1.0	-	pF	
Isolation resistance	Rs	R.H. ≤ 60 %, Vs = 500 V	1×10 ¹²	10 ¹⁴	-	Ω	
		AC, 60 s	5000	-	-) / mm a	
Isolation voltage	BVs	AC, 1 s, in oil	-	10000	-	Vrms	
		DC, 60 s, in oil	-	10000	-	Vdc	

Note: This device considered a two-terminal device: All pins on the LED side are shorted together, and all pin on the photodetector side are shorted together.

Switching Characteristics (Note) (Ta = -40 to 110 °C, unless otherwise specified)

Characteristics		Symbol	Test Circuit	Test	Condition	Min	Тур.*	Max	Unit
Propagation delay time	$L\toH$	tpLH			$I_F=0 \rightarrow 10 \ mA$	50	85	150	
(Note 9)	$H\toL$	tphl		Vcc2 = 30 V	$I_F = 10 \rightarrow 0 \text{ mA}$	50	90	150	
Output rise time (10-90 %) (Note 9)	tr		VCC2 = 30 V Rg = 10 Ω	$I_F = 0 \rightarrow 10 \text{ mA}$	-	32	-	
Output fall time (90-10 %)	(Note 9)	tf	11	C _g = 25 nF	$I_F = 10 \rightarrow 0 \text{ mA}$	-	18	-	ns
Pulse with distortion	(Note 9)	tpHL-tpLH		Duty = 50%	$I_F = 0 \leftrightarrow 10 \text{ mA}$	-	-	50	
Propagation delay skew (device to device)	(Note 9) (Note 10)	tpsk			$I_F = 0 \leftrightarrow 10 \text{ mA}$	-80	-	80	
DESAT Sense to 90% Del	lay	t _{DESAT(90%)}		C_{DESAT} = 100 pF, Rg = 10 Ω		-	180	500	
DESAT Sense to 10% Del	lay	t _{DESAT(10%)}		Cg = 25 nF, Vc R _F = 2.1 kΩ	CC2 = 30 V	-	3.5	5	μs
DESAT Sense to Low Lev FAULT Signal Delay	el	t _{DESAT(FAULT)}	12	C _{DESAT} = 100 pl	-	-	300	500	20
DESAT Sense to Low Pro Delay	pagation	t _{DESAT(LOW)}	12	Cg = 25 nF, Vc R _F = 2.1 kΩ	CC2 = 30 V	-	200	-	ns
DESAT Input Mute		$t_{\text{DESAT}(\text{MUTE})}$		C _F = Open		7	14	-	
RESET to High Level FAL Signal Delay	JLT	t _{reset(fault)}			$V_{CC1} = 5.5 \ V$	0.2	0.45	2	μS
Common Mode Transient at High Level Output	Immunity	СМн	13 to		I _F = 10 mA V _{O (min)} = 26 V	±35	-	-	k)//uo
Common Mode Transient at Low Level Output	Immunity	CML	16		$\begin{array}{l} I_F=0 \mbox{ mA} \\ V_{O \mbox{ (max)}}=1 \mbox{ V} \end{array}$	±35	-	-	kV/μs

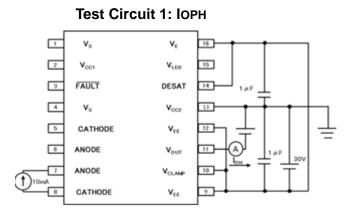
(*): All typical values are at Ta = 25 °C.

Note 9: Input signal (f = 10 kHz, duty = 50%, tr = tf = 5 ns or less)

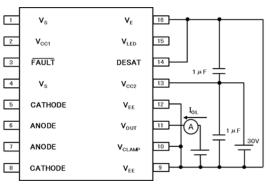
CL is approximately 15 pF which includes probe and stray wiring capacitance.

Note 10: The propagation delay skew, tpsk, is equal to the magnitude of the worst-case difference in tpHL and/or tpLH that will be seen between units at the same given conditions (supply voltage, input current, temperature, etc).

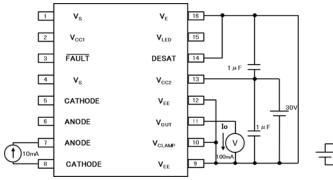
Test Circuit



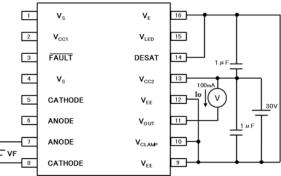
Test Circuit 2: IOPL



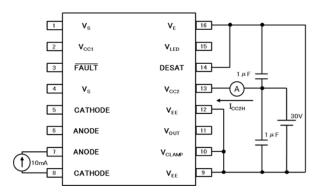
Test Circuit 3: VOн



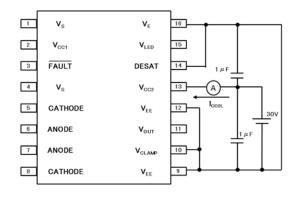
Test Circuit 4: VoL



Test Circuit 5: ICC2H

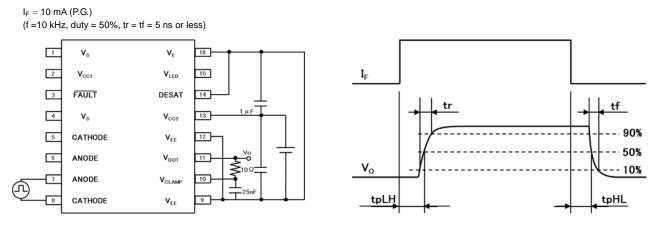


Test Circuit 6: ICC2L

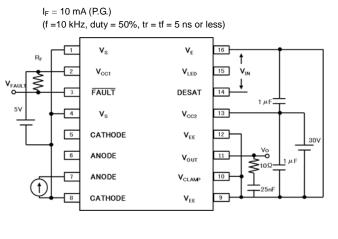


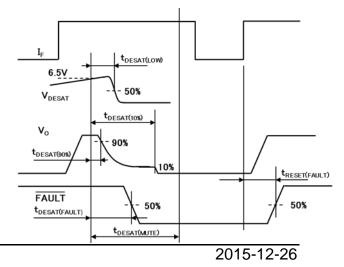
Test Circuit 7: ICHG 1 ٧s 1 ٧c Vs V_{E} 16 16 15 2 V_{CC1} VLED 15 2 V_{CC1} V_{LED} FAULT A 3 FAULT 3 DESAT DESAT 14 A 14 1 # F 1μF . CHG 4 13 4 ٧s 13 vs $V_{\rm CC2}$ $V_{\rm CC2}$ 5 5 CATHODE 12 CATHODE V_{EE} 12 V_{EE} 30 30 6 11 ANODE 11 6 ANODE Vout Vout $1 \mu F$ 10 7 10 ANODE ANODE VCIAND 7 VCLAME 1)10mA CATHODE V_{EE} 9 8 CATHODE V_{EE} 9 **-**8 Test Circuit 9: VUVLO Test Circuit 10: IFLH 1 ٧s ٧_E 16 1 $V_{\rm S}$ \mathbf{V}_{E} 16 2 V_{cc1} V_{LED} 15 2 V_{CC1} V_{LED} 15 3 FAULT 14 FAULT DESAT 3 1μF 1 # F DESAT 14 13 4 vs 4 $V_{\rm CC2}$ 13 \mathbf{v}_{s} V_{CC2} 5 CATHODE V_{EE} 12 5 CATHODE 12 V_{EE} **V**o •• v_o 11 6 ANODE 6 11 Vout ANODE Vout ANODE 10 ANODE 10 Ē 7 ᠿ 10mA $\widehat{}$ CATHODE CATHODE 8 V_{EE} 9 8 V_{EE} 9

Test Circuit 11: tpLH, tpHL, tr, tf, | tpHL-tpLH |

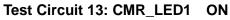


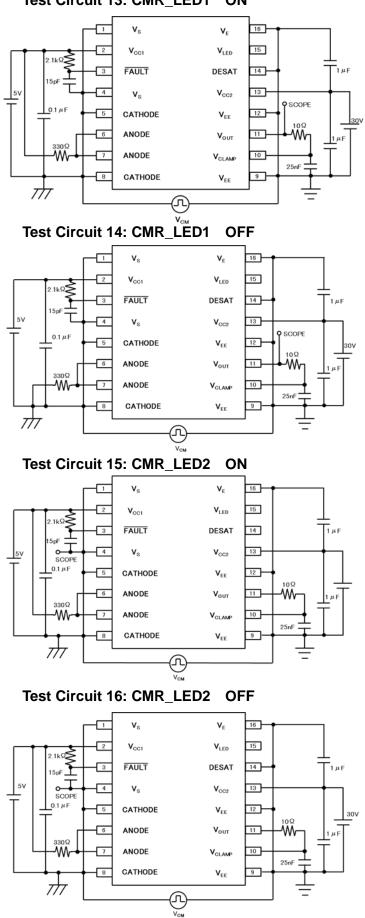
Test Circuit 12: tdesat(90%), tdesat(10%), tdesat(fault), tdesat(Low), tdesat(mute), treset(fault)





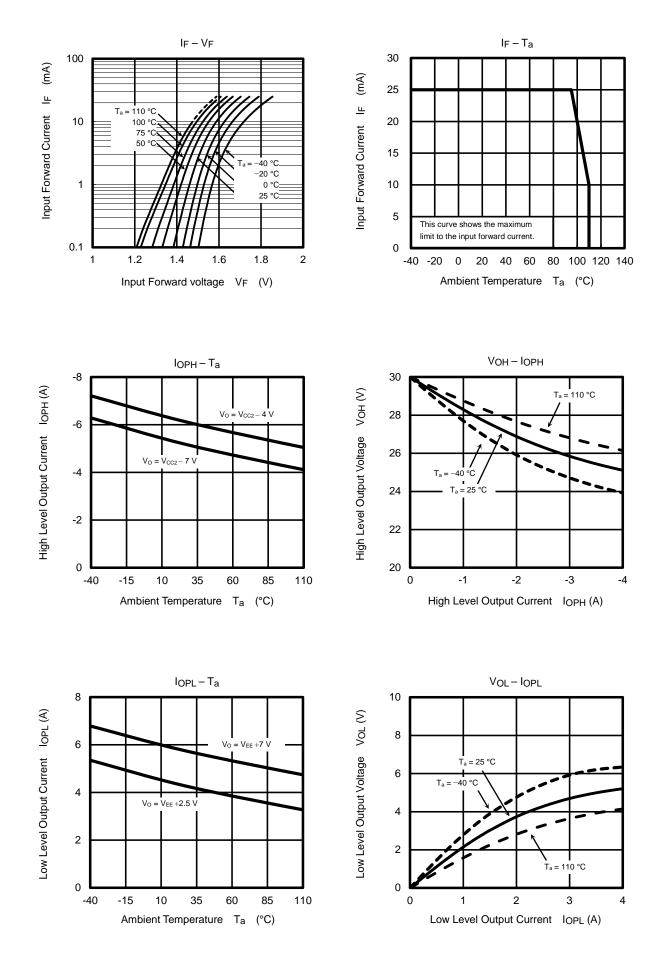


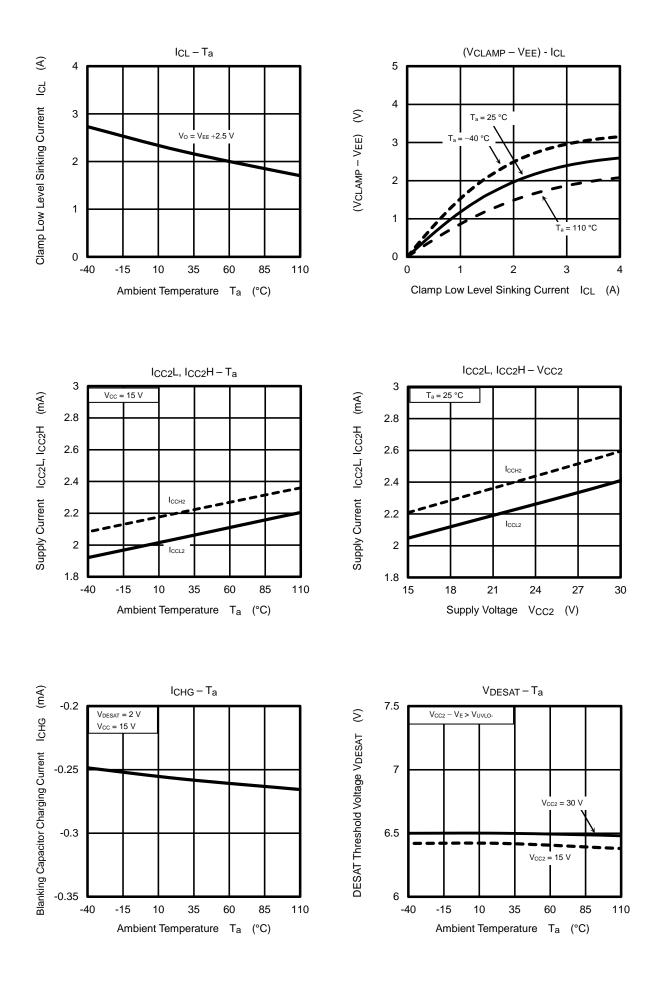


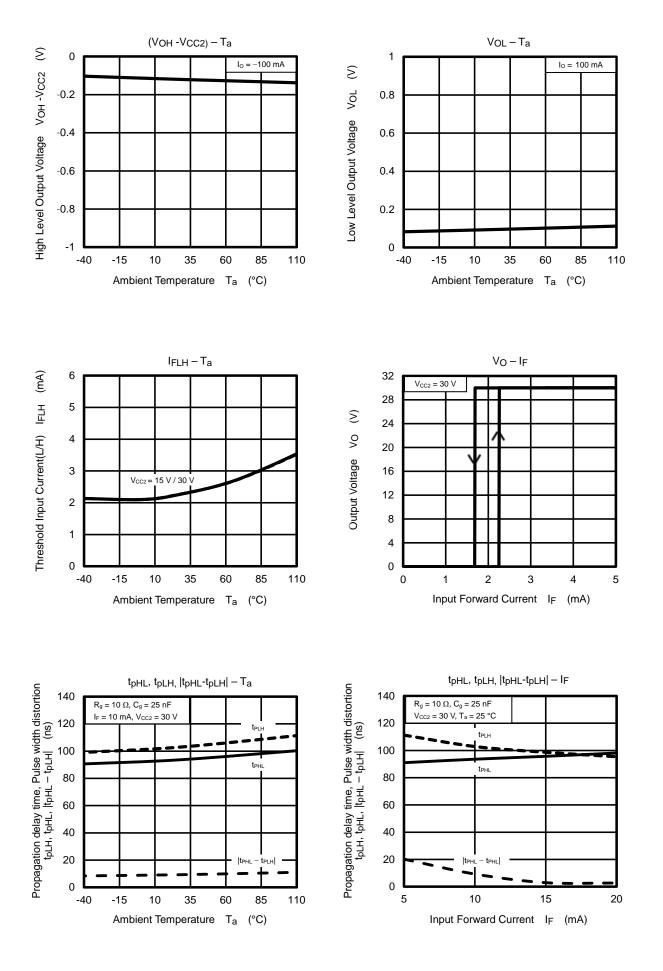


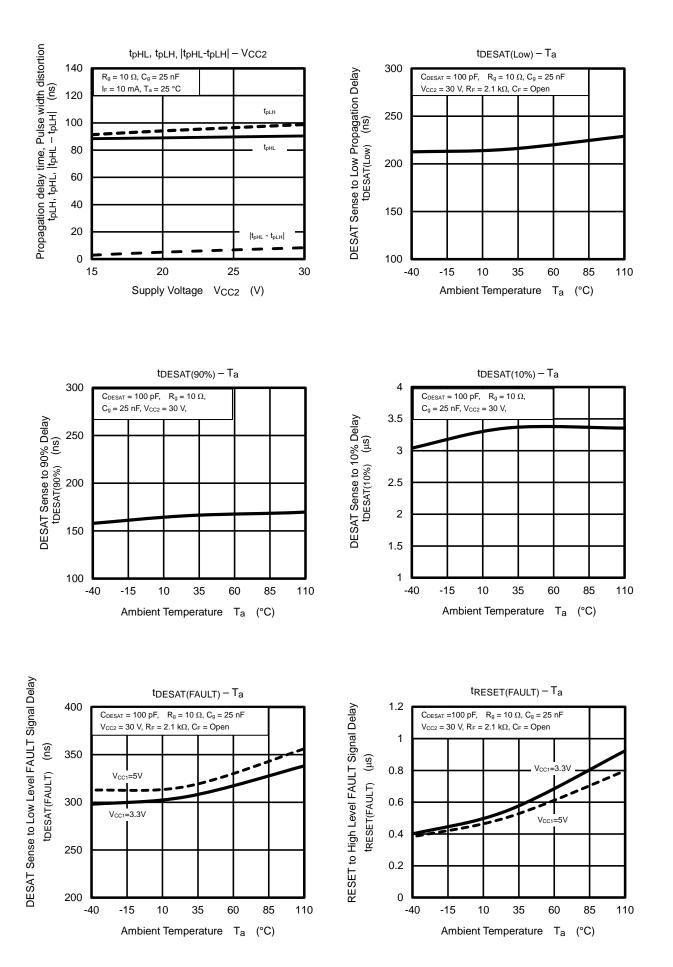
CM_L (CM_H) is the maximum rate of rise (fall) of the common mode voltage that can be sustained with the output voltage in the LOW (HIGH) state.

Characteristics Curve









PRECAUTIONS OF SURFACE MOUNTING TYPE PHOTOCOUPLER SOLDERING &

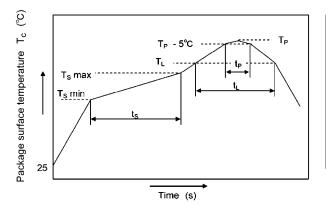
GENERAL STORAGE

(1) Precautions for Soldering

The soldering temperature should be controlled as closely as possible to the conditions shown below, irrespective of whether a soldering iron or a reflow soldering method is used.

1) When Using Soldering Reflow

An example of a temperature profile when lead(Pb)-free solder is use



	Symbol	Min	Max	Unit
Preheat temperature	Τs	150	200	°C
Preheat time	ts	60	120	s
Ramp-up rate $(T_L \text{ to } T_P)$			3	°C/s
Liquidus temperature	ΤL	2 [.]	17	°C
Time above T _L	tL	60	150	S
Peak temperature	Τ _Ρ		260	°C
Time during which T_c is between ($T_P - 5$) and T_P	t _P		30	s
Ramp-down rate $(T_P \text{ to } T_L)$			6	°C/s

An Example of a Temperature Profile When Lead(Pb)-Free Solder Is Used

- Reflow soldering must be performed once or twice.
- The mounting should be completed with the interval from the first to the last mountings being 2 weeks.

2) When using soldering Flow

- Apply preheating of 150 °C for 60 to 120 seconds.
- Mounting condition of 260 °C or less within 10 seconds is recommended.
- Flow soldering must be performed once

3) When using soldering Iron

• Complete soldering within 10 seconds for lead temperature not exceeding 260 °C or within 3 seconds not exceeding 350 °C.

• Heating by soldering iron must be only once per 1 lead

(2) Precautions for General Storage

- 1) Do not store devices at any place where they will be exposed to moisture or direct sunlight.
- 2) When transportation or storage of devices, follow the cautions indicated on the carton box.
- 3) The storage area temperature should be kept within a temperature range of 5 degree C to 35 degree C, and relative humidity should be maintained at between 45% and 75%.
- 4) Do not store devices in the presence of harmful (especially corrosive)gases, or in dusty conditions.
- 5) Use storage areas where there is minimal temperature fluctuation. Because rapid temperature changes can cause condensation to occur on stored devices, resulting in lead oxidation or corrosion, as a result, the solderability of the leads will be degraded.
- 6) When repacking devices, use anti-static containers.
- 7) Do not apply any external force or load directly to devices while they are in storage.
- 8) If devices have been stored for more than two years, even though the above conditions have been followed, it is recommended that solderability of them should be tested before they are used.

Specifications for Embossed-Tape Packing (TP) for SO16L Coupler

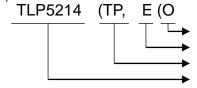
1. Applicable Package

Package	Product Type
SO16L	Long creepage Coupler

2. Product Naming System

Type of package used for shipment is denoted by a symbol suffix after a product number. The method of classification is as below.

(Example)



Domestic ID (Country / Region of origin: Japan) [[G]]/RoHS COMPATIBLE (Note) Tape type Device name

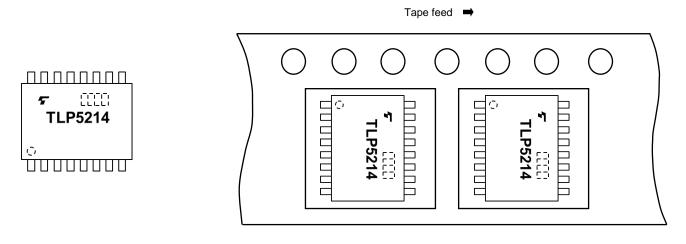
Note : Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronics equipment.

3. Tape Dimensions

3.1 Orientation of Device in Relation to Direction of Tape Movement

Device orientation in the recesses is as shown in Figure 1.





3.2 Packing Quantity: 1500 per reel

3.3 Empty Device Recesses Are as Shown in Table 1.

Table1	Empty	Device	Recesses
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	Standard	Remarks	
Occurrences of 2 or more successive empty device recesses	0 device	Within any given 40-mm section of tape, not including leader and trailer	
Single empty device recesses	6 device (max) per reel	Not including leader and trailer	

3.4 Start and End of Tape

The start of the tape has 14 or more empty holes. The end of the tape has 34 or more empty holes and more than 30mm only for a cover tape.

3.5 Tape Specification

- (1) Material: Plastic (for protection against static electricity)
- (2) Dimensions: The tape dimensions are shown in Figure 2 and Table 2.

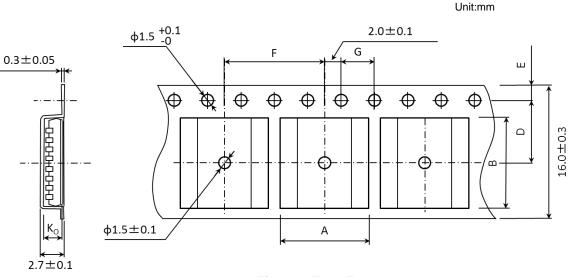


Figure 2 Tape Forms

Table 2 Tape Dimensions

Unit: mm

8		Unless otherwise specified: ±0.1
Symbol	Dimension	Remark
A	10.4	—
В	10.7	—
D	7.5	Center line of indented square hole and sprocket hole
E	1.75	Distance between tape edge and hole center
F	12.0	Cumulative error +0.1 (max) per 10 feed holes
G	4.0	Cumulative error $^{+0.1}_{-0.3}$ (max) per 10 feed holes
K ₀	2.4	Internal space

3.6 Reel

- (1) Material: Plastic
- (2) Dimensions: The reel dimensions are as shown in Figure 3 and Table 3.

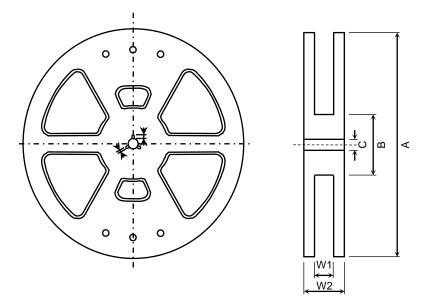


Table 3 F	Reel Dimension
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	Unit: mm
Symbol	Dimension
А	Φ330 ± 2
В	Φ100 ± 1
С	Φ13 ± 0.5
E	2.0 ± 0.5
U	4.0 ± 0.5
W1	17.4 ± 1.0
W2	21.4 ± 1.0

Figure 3 Reel Forms

4. Packing

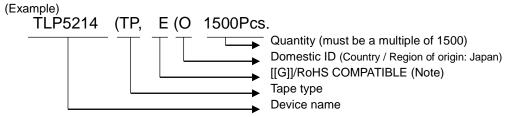
Either one reel or ten reels of photocoupler are packed in a shipping carton.

5. Label Indication

The carton bears a label indicating the product number, the symbol representing classification of standard, the quantity, the lot number and Toshiba company name.

6. Ordering Method

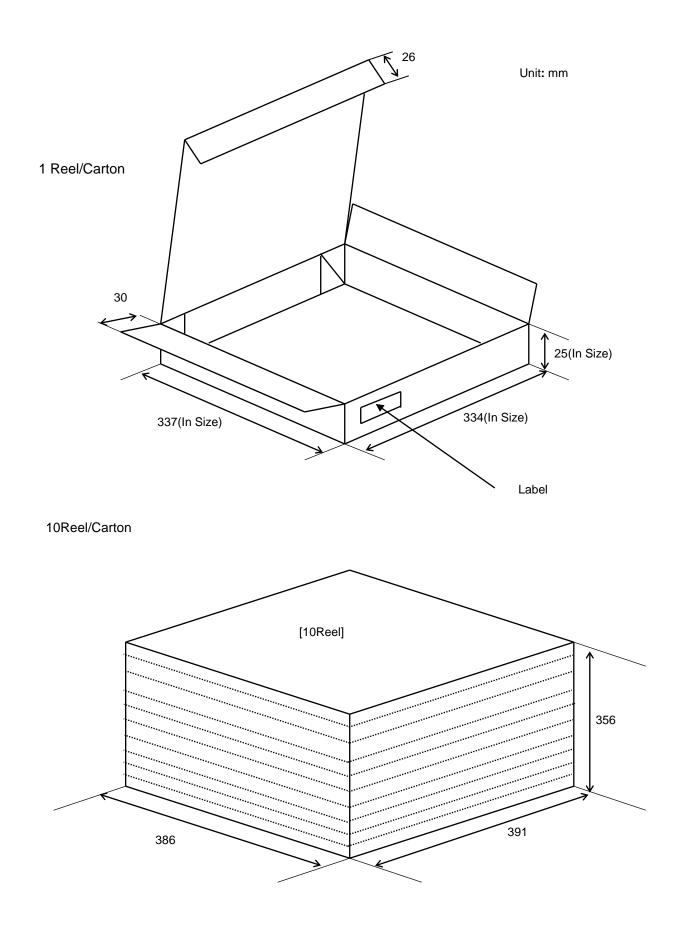
When placing an order, please specify the product number, the CTR rank, the tape and the quantity as shown in the following example.



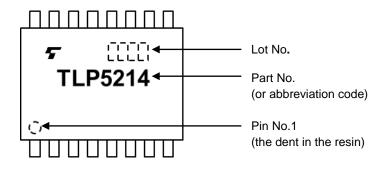
Note : Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronics equipment.

7. Packing Dimensions (ϕ 330 mm)



8. Marking



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